

Afisarea articolelor 1-6(6) pentru cuvântul-cheie "Film growth"

Hot wall beam epitaxial growth of PbTe layers on BaF₂/CaF₂/Si(111) substrates

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Synthesis and characterization of functional nanostructured zinc oxide thin films

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ECS Transactions

Vol. 3, Ediția 9. 2006. Pennington, New Jersey. [ISBN 1566775094, 1566775094, 978-156677509-0](https://doi.org/10.1109/1566775094_1566775094_978-156677509-0).

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Growth and characterization of crack-free GaN films grown on cracked Si-doped GaN templates

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About the edge luminescence of cadmium sulphide thin layers grown on molybdenum

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Epitaxial relations in BaF₂ films grown by MBE on Si(111) substrates

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Raman scattering analysis of InGaAs/InP: Effect of rare earth (Dysprosium) addition during liquid phase epitaxial growth

Tighineanu Ion, Ursachi Veaceslav, Podor Balint, Csontos L., Şontea Victor

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